



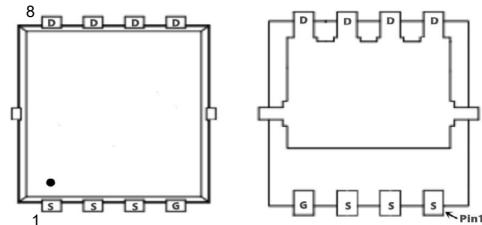
PJM50N60DL

N-Channel Enhancement Mode Power MOSFET

Features

- Excellent $R_{DS(ON)}$ and Low Gate Charge
- $V_{DS} = 60V, I_D = 50A$
- $R_{DS(on)} < 16m\Omega @ V_{GS} = 10V$

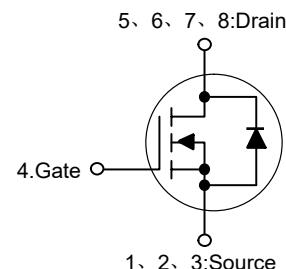
PDFN3x3-8L



Schematic Diagram

Applications

- Battery protection
- Load Switch
- Uninterruptible power supply



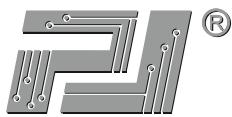
Absolute Maximum Ratings

Ratings at 25°C Case temperature unless otherwise specified.

| Parameter | Symbol | Value | Unit |
|--|-----------|-------------|------|
| Drain-Source Voltage | V_{DS} | 60 | V |
| Gate-Source Voltage | V_{GS} | ± 20 | V |
| Drain Current-Continuous at $V_{GS}=10V$ ^{Note1} | I_D | 50 | A |
| Drain Current-Pulsed ^{Note2} | I_{DM} | 90 | A |
| Single Pulse Avalanche Energy ^{Note3} | E_{AS} | 39.2 | mJ |
| Avalanche Current | I_{AS} | 38 | A |
| Maximum Power Dissipation ^{Note4} | P_D | 45 | W |
| Junction Temperature | T_J | 150 | °C |
| Storage Temperature Range | T_{STG} | -55 to +150 | °C |

Thermal Characteristics

| | | | |
|--|-----------------|-----|------|
| Thermal Resistance, Junction-to-Ambient ^{Note1} | $R_{\theta JA}$ | 62 | °C/W |
| Maximum Junction-to-Case ^{Note1} | $R_{\theta JC}$ | 2.8 | °C/W |



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Electrical Characteristics

(T_J=25°C unless otherwise specified)

| Parameter | Symbol | Test Condition | Min. | Typ. | Max. | Unit |
|---|----------------------|---|------|------|------|------|
| Static Characteristics | | | | | | |
| Drain-Source Breakdown Voltage | V _{(BR)DSS} | V _{GS} =0V, I _D =250μA | 60 | 65 | -- | V |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =48V, V _{GS} =0V | -- | -- | 1 | μA |
| Gate-Body Leakage Current | I _{GSS} | V _{GS} =±20V, V _{DS} =0V | -- | -- | ±100 | nA |
| Gate Threshold Voltage ^{Note2} | V _{GS(th)} | V _{DS} =V _{GS} , I _D =250μA | 1.2 | 1.8 | 2.5 | V |
| Drain-Source On-Resistance ^{Note2} | R _{DS(on)} | V _{GS} =10V, I _D =20A | -- | 11 | 16 | mΩ |
| | | V _{GS} =4.5V, I _D =10A | -- | 16 | 20 | mΩ |
| Forward Transconductance ^{Note2} | g _{FS} | V _{DS} =5V, I _D =15A | -- | 45 | -- | S |
| Dynamic Characteristics | | | | | | |
| Input Capacitance | C _{iss} | V _{DS} =15V, V _{GS} =0V, f=1MHz | -- | 2423 | -- | pF |
| Output Capacitance | C _{oss} | | -- | 145 | -- | pF |
| Reverse Transfer Capacitance | C _{rss} | | -- | 97 | -- | pF |
| Switching Characteristics | | | | | | |
| Turn-on Delay Time | t _{d(on)} | V _{DD} =30V, I _D =15A V _{GS} =10V, R _G =3.3Ω | -- | 7.2 | -- | nS |
| Turn-on Rise Time | t _r | | -- | 50 | -- | nS |
| Turn-off Delay Time | t _{d(off)} | | -- | 36.4 | -- | nS |
| Turn-off Fall Time | t _f | | -- | 7.6 | -- | nS |
| Total Gate Charge | Q _g | V _{DS} =48V, I _D =15A, V _{GS} =4.5V | -- | 19.3 | -- | nC |
| Gate-Source Charge | Q _{gs} | | -- | 7.1 | -- | nC |
| Gate-Drain Charge | Q _{gd} | | -- | 7.6 | -- | nC |
| Source-Drain Diode Characteristics | | | | | | |
| Diode Forward Voltage ^{Note2} | V _{SD} | V _{GS} =0V, I _S =1A | -- | -- | 1 | V |
| Diode Forward Current ^{Note1,5} | I _S | | -- | -- | 35 | A |

Note :

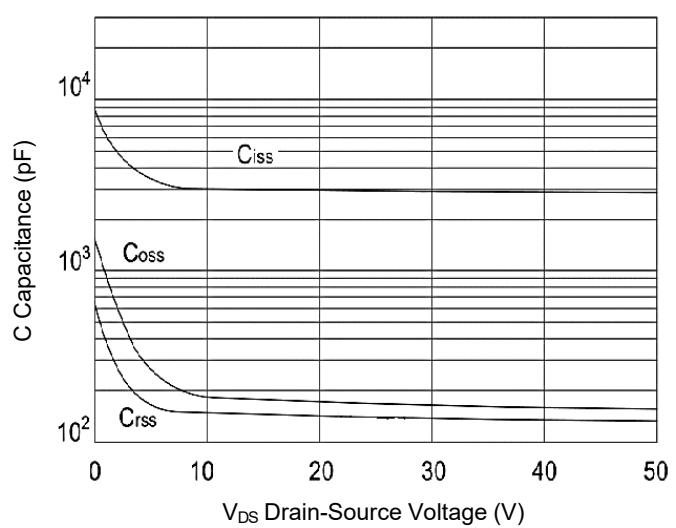
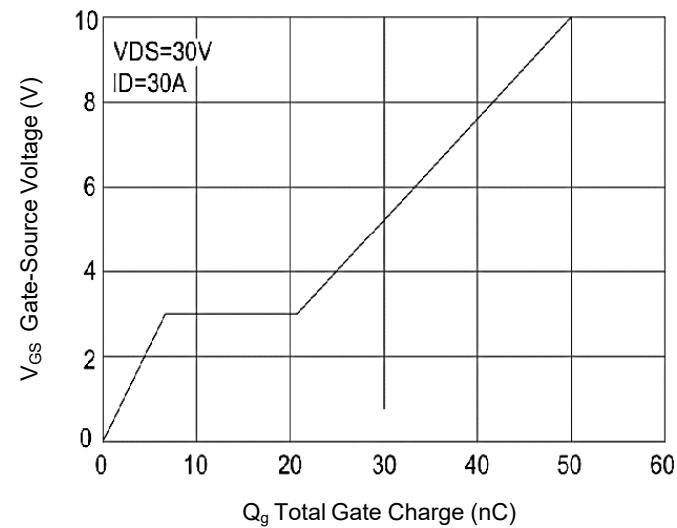
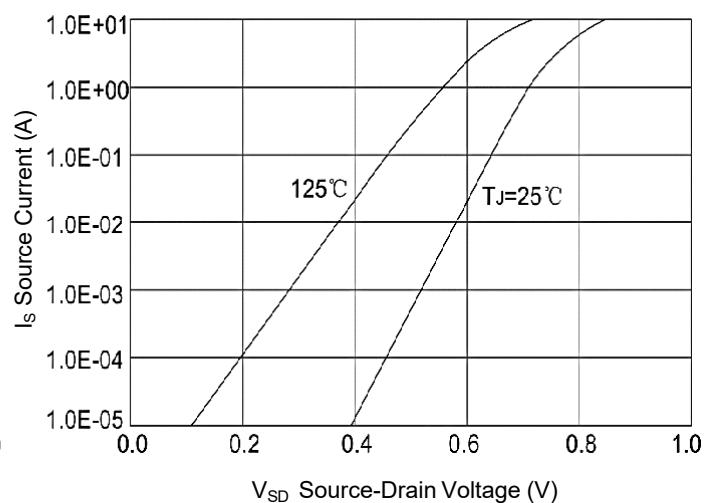
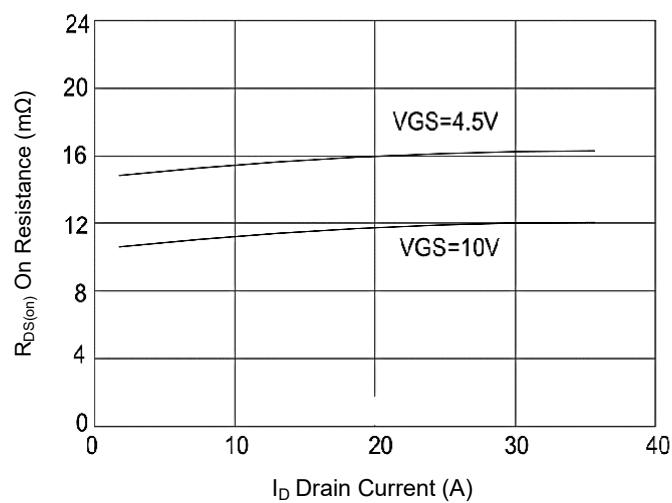
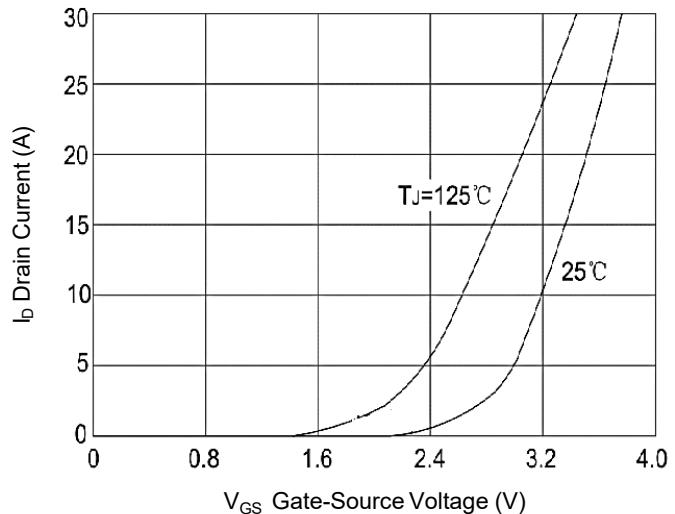
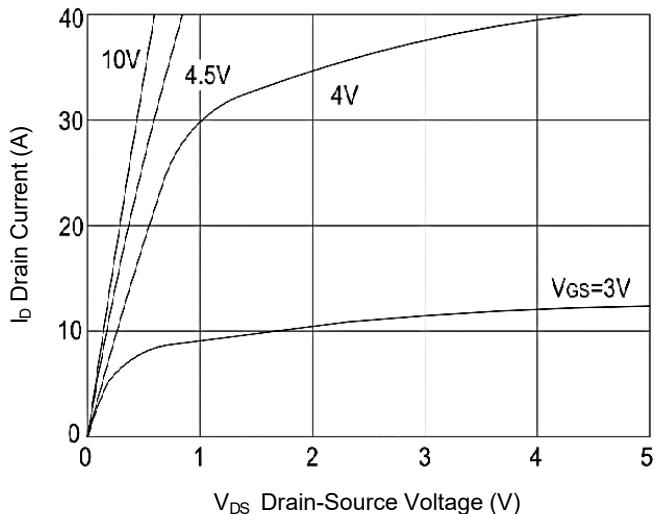
- 1.The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper.
- 2.The data tested by pulsed , pulse width≤ 300us , duty cycle ≤ 2%
- 3.The E_{AS} data shows Max. rating . The test condition is V_{DD}=25V,V_{GS}=10V,L=0.1mH,I_{AS}=38A
- 4.The power dissipation is limited by 150°C junction temperature
- 5.The data is theoretically the same as I_D and I_{DM} , in real applications , should be limited by total power dissipation.



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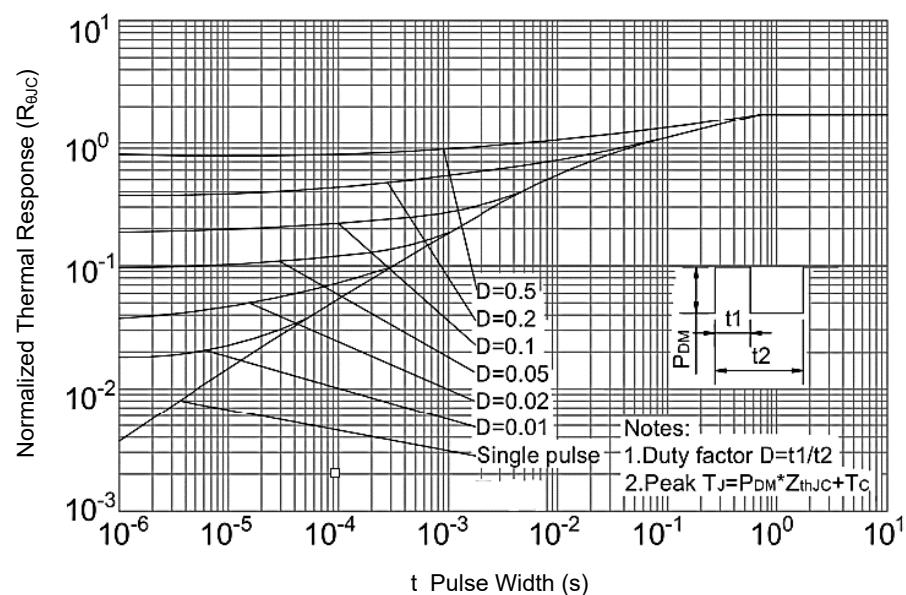
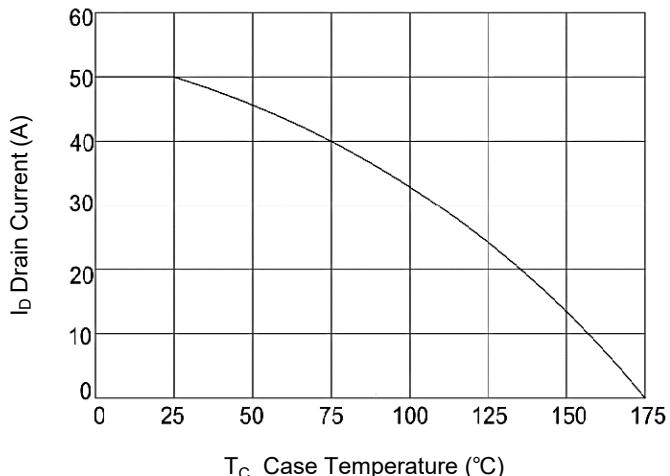
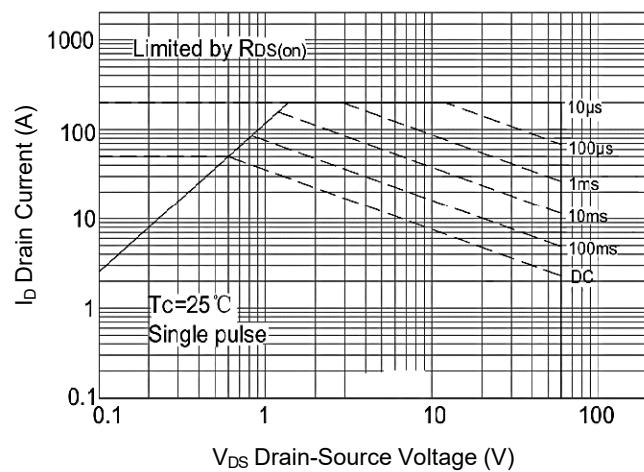
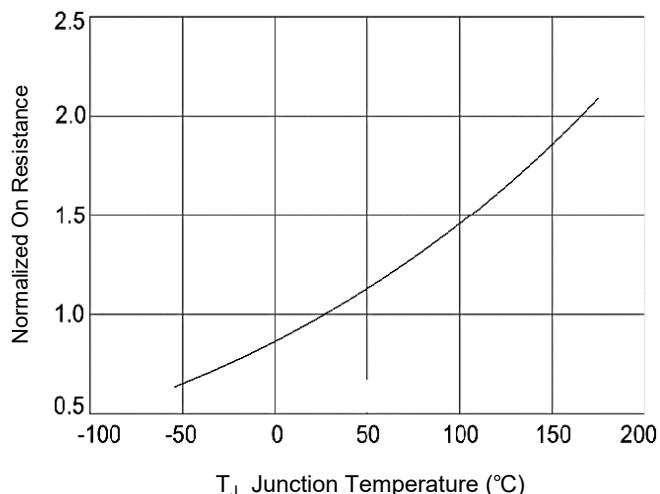
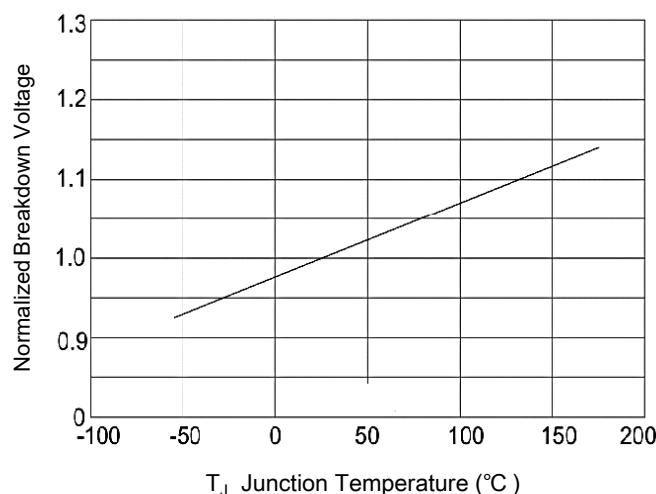
Typical Characteristic Curves





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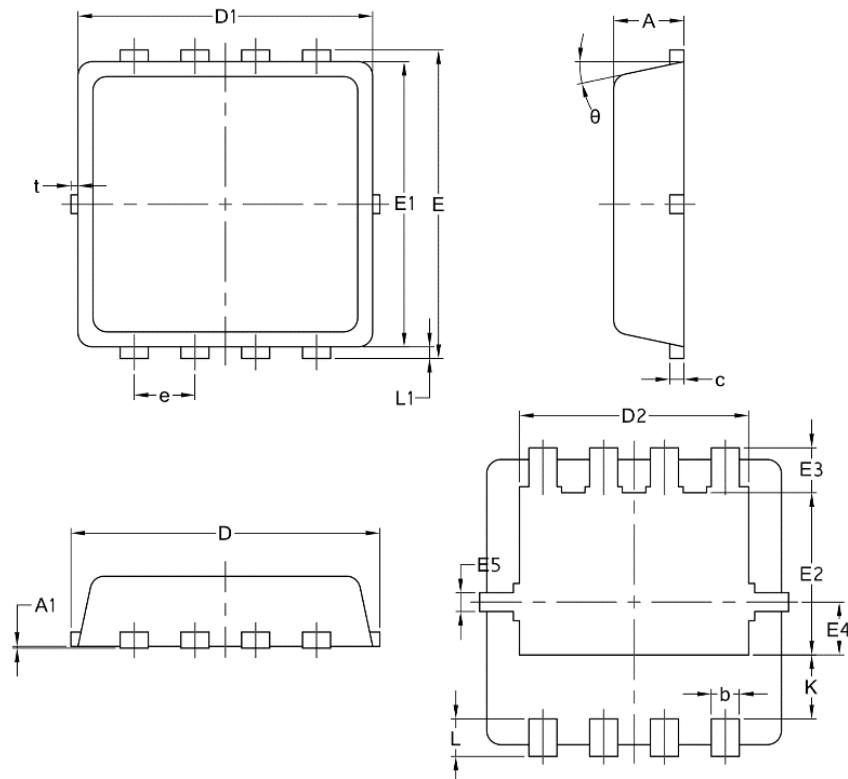




Package Outline

PDFN3x3-8L

Dimensions in mm



| Symbol | Common mm | | |
|--------|--------------|-------|------|
| | Mim | Nom | Max |
| A | 0.70 | 0.75 | 0.85 |
| A1 | / | / | 0.05 |
| b | 0.20 | 0.30 | 0.40 |
| c | 0.10 | 0.152 | 0.25 |
| D | 3.15 | 3.30 | 3.45 |
| D1 | 3.00 | 3.15 | 3.25 |
| D2 | 2.29 | 2.45 | 2.65 |
| E | 3.15 | 3.30 | 3.45 |
| E1 | 2.90 | 3.05 | 3.20 |
| E2 | 1.54 | 1.74 | 1.94 |
| E3 | 0.28 | 0.48 | 0.65 |
| E4 | 0.37 | 0.57 | 0.77 |
| E5 | 0.10 | 0.20 | 0.30 |
| e | 0.60 | 0.65 | 0.70 |
| K | 0.59 | 0.69 | 0.89 |
| L | 0.30 | 0.40 | 0.50 |
| L1 | 0.06 | 0.125 | 0.20 |
| t | 0 | 0.075 | 0.13 |
| Φ | 10 | 12 | 14 |